

TLP227GA, TLP227GA-2

Modem

Telecommunications

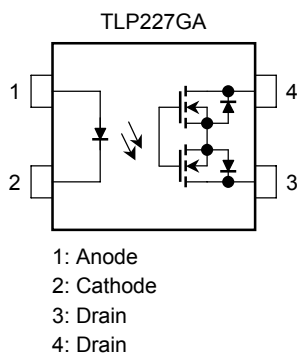
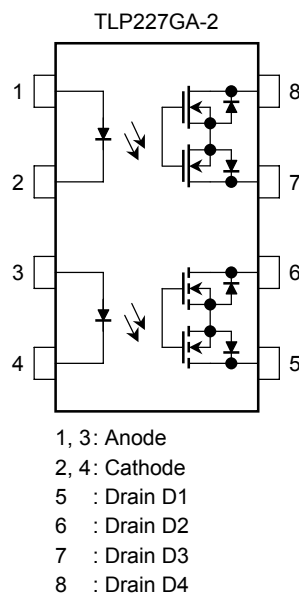
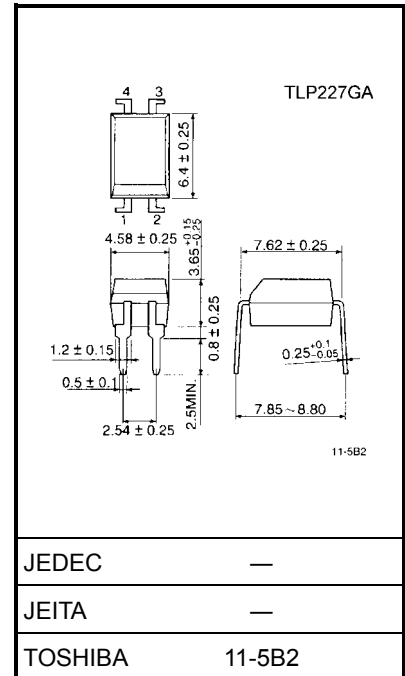
PBXs

Unit: mm

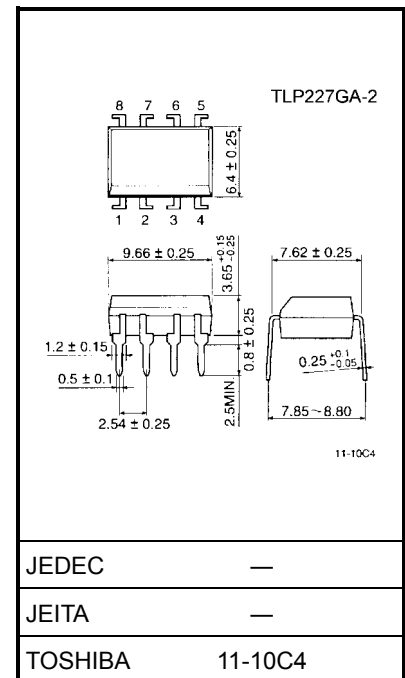
The Toshiba TLP227GA series consist of a gallium arsenide infrared-emitting diode optically coupled to a photo-MOSFET in a 4-pin DIP or a 8-pin DIP package, and has a peak off-State voltage of 400 V.

- Normally off function
- TLP227GA : DIP4 (1 form A)
TLP227GA-2 : DIP8 (2 form A)
- Peak off-state voltage : 400 V (min)
- Trigger LED current : 3 mA (max)
- On-state current : 120 mA (max)
- On-state resistance : 35Ω (max)
- Isolation voltage : 2500 Vrms (min)

Pin Configuration (top view)



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)

Maximum Rating (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
Led	Forward current		I _F	50	mA	
	Forward current derating (Ta ≥ 25°C)		ΔI _F /°C	−0.5	mA/°C	
	Peak forward current (100 μs pulse, 100 pps)		I _{FP}	1	A	
	Reverse voltage		V _R	5	V	
	Junction temperature		T _j	125	°C	
Detector	Off-state output terminal voltage		V _{OFF}	400	V	
	On-state current	TLP227GA		I _{ON}	120	Ma
		TLP227GA-2	One channel			
			Both channel			
	On-state current rating (Ta ≥ 25°C)	TLP227GA		ΔI _{ON} /°C	−1.2	mA/°C
		TLP227GA-2	One channel			
			Both channel			
	Junction temperature		T _j	125	°C	
Storage temperature range		T _{stg}	−55~125	°C		
Operating temperature range		T _{opr}	−40~85	°C		
Lead soldering temperature (10 s)		T _{sol}	260	°C		
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)		BV _S	2500	Vrms		

Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	320	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	100	mA
Operating temperature	T_{opr}	-20	—	65	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Led	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 400 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	—	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
On-state resistance	R_{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	18	35	Ω

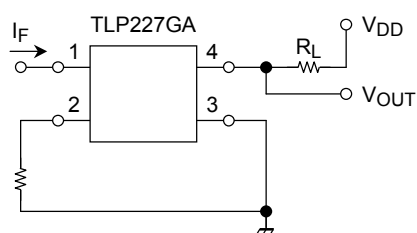
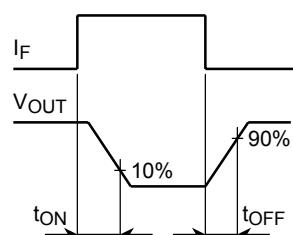
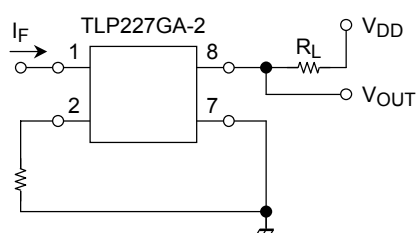
Isolation Characteristics (Ta = 25°C)

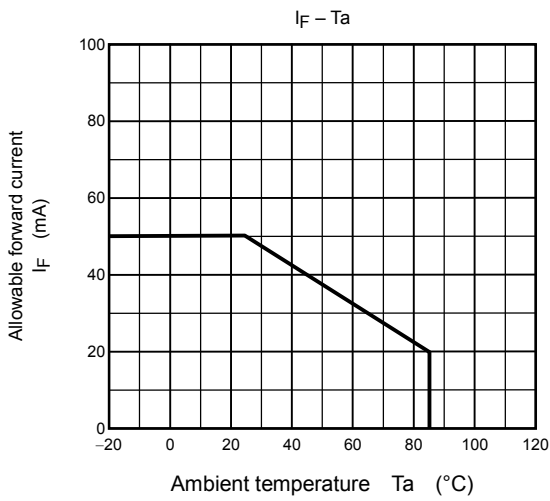
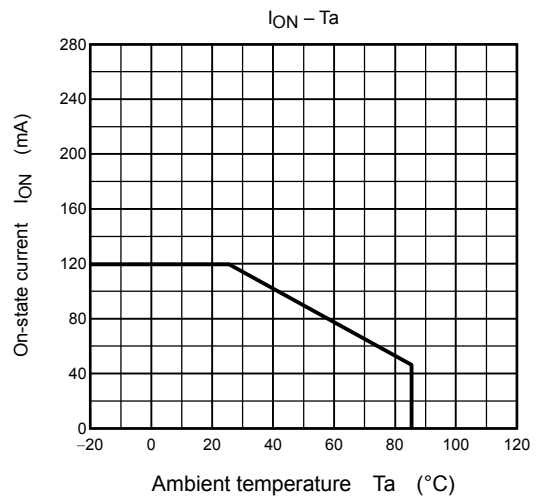
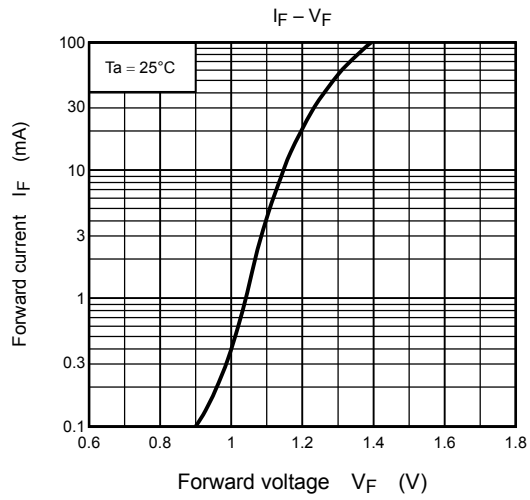
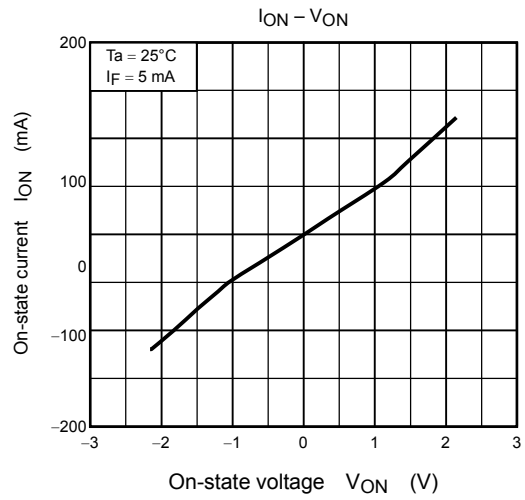
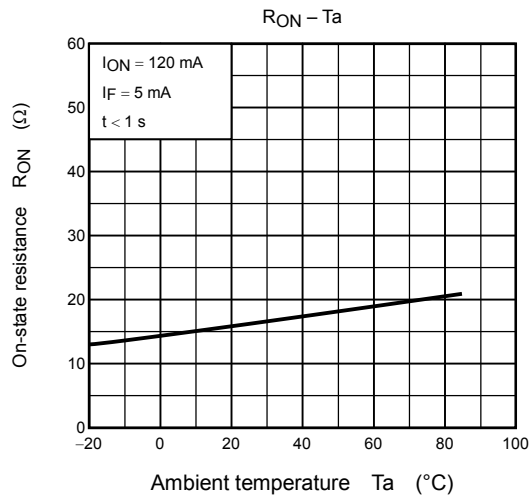
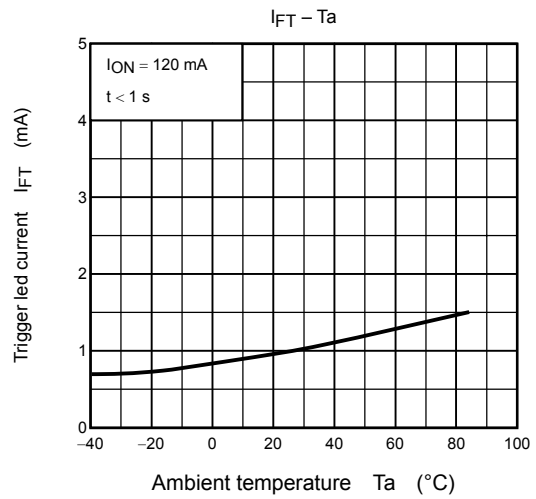
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, R.H. \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 min	2500	—	—	Vrms
		AC, 1 s (in oil)	—	5000	—	
		DC, 1 min (in oil)	—	5000	—	Vdc

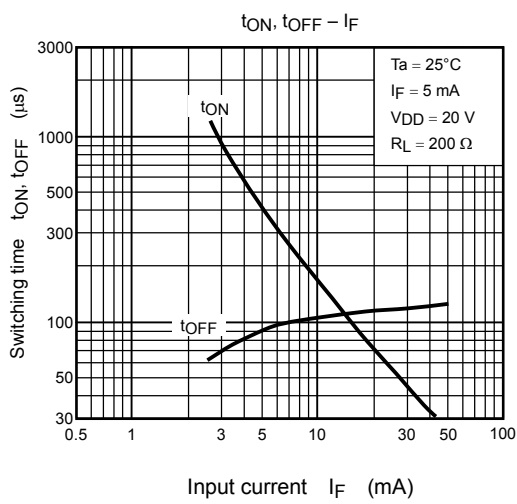
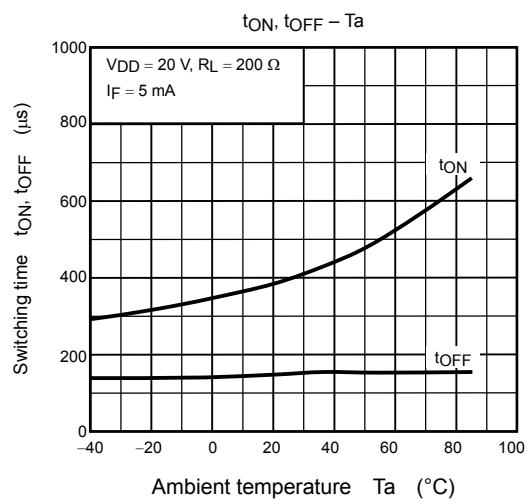
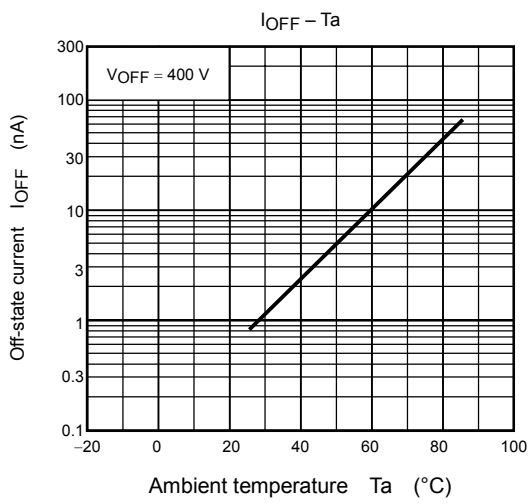
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 2)	—	—	1	ms
Turn-off time	t_{OFF}		—	—	1	

Note 2: Switching time test circuit







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